NSN 5962-01-180-3467

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-180-3467 **Body Length:** Between 1.240 inches and 1.280 inches **Body Width:** 0.530 inches **Body Height:** 0.170 inches **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Programmable and monolithic and hermetically sealed **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 13 input **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** 7.0 volts power source **Time Rating Per Chacteristic:** 70.00 nanoseconds propagation delay time, low to high level output **Memory Device Type:** Rom **Test Data Document:** 05869-726030-2 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 24 printed circuit Shelf Life: N/a

Demilitarization: Yes - demil/mli

Unit Of Measure:

Fiig:

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